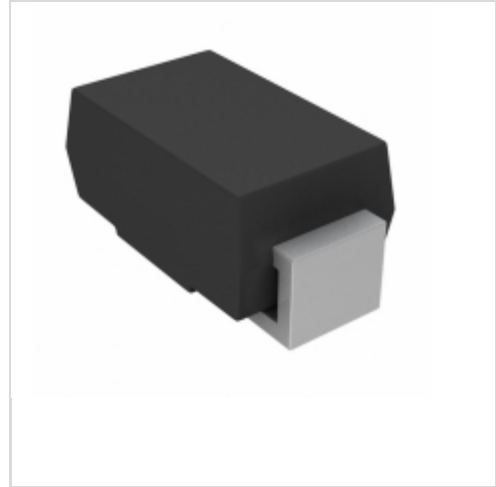


BYG24GHE3/TR3



Vishay / Semiconductor - Diodes Division

DIODE AVALANCHE 400V 1.5A

Lead free / RoHS Compliant

Discrete Semiconductor Products

1.BYG24GHE3/TR3.pdf

2.BYG24GHE3/TR3.pdf

Buy Now

Out Stock

0 pcs

Minimum:1

Multiples:100

Manufacturer lead time 10 weeks

We can supply BYG24GHE3/TR3, use the request quote form to request BYG24GHE3/TR3 price and lead time. Zeano is a professional electronic components distributor. With 3+ Million line items of available electronic components can ship in short lead-time, over 250 thousand part numbers of electronic components in stock for immediately delivery, which may include part number BYG24GHE3/TR3. The price and lead time for BYG24GHE3/TR3 depending on the quantity required and warehouse location. Contact us and our sales representative will provide you price. We look forward to work with you.

Shopping Process

1

Confirm the product

2

submit the order

3

payment

4

wait for delivery

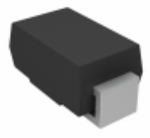
5

receive the goods

Specifications

Voltage - Forward (Vf) (Max) @ If:	1.25V @ 1.5A
Voltage - DC Reverse (Vr) (Max):	400V
Supplier Device Package:	DO-214AC (SMA)
Speed:	Fast Recovery = 200mA (Io)
Series:	-
Reverse Recovery Time (trr):	140ns
Packaging:	Tape & Reel (TR)
Package / Case:	DO-214AC, SMA
Operating Temperature - Junction:	-55°C ~ 150°C
Mounting Type:	Surface Mount
Diode Type:	Avalanche
Current - Reverse Leakage @ Vr:	1µA @ 400V
Current - Average Rectified (Io):	1.5A
Capacitance @ Vr, F:	-

Related products

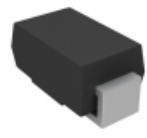


BYG24J-E3/TR

DIODE AVALANCHE 600V 1.5A

Vishay Semiconductor Diodes Division

RFQ

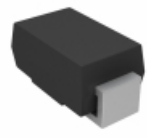


BYG24G-E3/TR

DIODE AVALANCHE 400V 1.5A

Vishay Semiconductor Diodes Division

RFQ

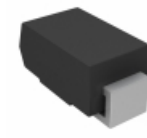


BYG24G-M3/TR3

DIODE AVALANCHE 400V 1.5A

Vishay Semiconductor Diodes Division

RFQ

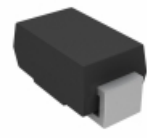


BYG24GHM3/TR3

DIODE AVALANCHE 400V 1.5A

Vishay Semiconductor Diodes Division

RFQ

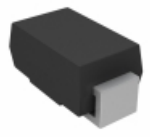


BYG24G-E3/TR3

DIODE AVALANCHE 400V 1.5A

Vishay Semiconductor Diodes Division

RFQ



BYG24G-M3/TR

DIODE AVALANCHE 400V 1.5A

Vishay Semiconductor Diodes Division

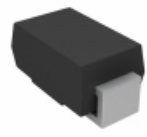
RFQ



BYG24J-E3/HE3

VISHAY

RFQ



BYG24GHM3/TR

DIODE AVALANCHE 400V 1.5A

Vishay Semiconductor Diodes Division

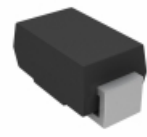
RFQ



BYG24J

VISHAY

RFQ



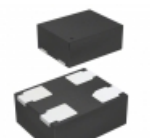
BYG24GHE3/TR

DIODE AVALANCHE 400V 1.5A

Vishay Semiconductor Diodes Division

RFQ

Guess You May Looking For

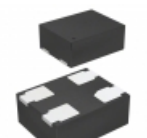


SIT1602BI-73-XXS-60.000000E

-40 TO 85C, 2016, 50PPM, 2.25V-3

SITIME

RFQ

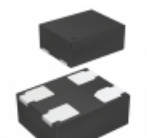


SIT1602BI-73-XXS-35.840000D

-40 TO 85C, 2016, 50PPM, 2.25V-3

SITIME

RFQ



SIT1602BC-71-25E-74.176000E

-20 TO 70C, 2016, 20PPM, 2.5V, 7

SITIME

RFQ



SIT1602BI-33-33N-18.432000Y

-40 TO 85C, 5032, 50PPM, 3.3V, 1

SITIME

RFQ



SIT1602BI-72-33N-66.666660D

-40 TO 85C, 2016, 25PPM, 3.3V, 6

SITIME

RFQ



SIT1602BC-32-25E-33.300000T

-20 TO 70C, 5032, 25PPM, 2.5V, 3

SITIME

RFQ

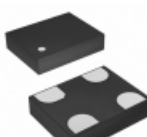


SIT1602BI-11-30E-24.000000E

-40 TO 85C, 2520, 20PPM, 3.0V, 2

SITIME

RFQ

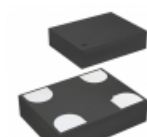


SIT1602BI-22-30E-40.500000E

-40 TO 85C, 3225, 25PPM, 3.0V, 4

SITIME

RFQ



SIT8008AI-22-33E-80.000000D

OSC MEMS 80.0000MHZ LVCMOS SMD

SITIME

RFQ



SIT8008BI-12-28E-96.000000D

OSC MEMS 96.0000MHZ LVCMOS SMD

SITIME

RFQ